IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Lee, et al. Attorney Docket: TSM03-0587

Filed: Herewith Examiner: TBD

Serial No.: TBD Art Unit: TBD

For: Semiconductor Structure having a Strained Region and a Method of Fabricating Same

Mail Stop: Patent Application Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Dear Sir:

The Applicants wish to bring to the attention of the Patent and Trademark Office the information noted on the enclosed substitute for form 1449A/PTO that may be considered material to the examination of the above-identified application.

No fee is due at this time, as this Information Disclosure Statement is being filed concurrently with the patent application.

Cite numbers 1-15 are newly cited prior art being filed under the waived requirement of 37 CFR 1.98 (a)(2)(i) dated July 11, 2003, therefore, copies of these U.S. patents and publications are not included.

Respectfully submitted,

September 8, 2003

Date

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Substitute for form 1449A/PTO				Complete if Known		
				Application Number	TBD	
	INFORMATION DIS	CLOSU	JRE	Filing Date	Herewith	
	STATEMENT BY A	PPLICA	NT	First Named Inventor	Lee, et al.	
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	(use as many sheets as necessary)			Examiner Name	TBD	
Sheet	1	of	1	Attorney Docket Number	TSM03-0587	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
		Number - Kind Code ^{2 (if known)}				
	1	US-5,221,367	06-22-1993	Chisholm, et al.		
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document		
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		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the		
Examiner Initials*	Cite ₁ No.	item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue	T [*]	
		number(s), publisher, city and/or country where published.		
_	16	SCHLUETER, J., "Trench Warfare: CMP and Shallow Trench Isolation," Semiconductor International, October 1999.		
-	17	TARASCHI, G., "Strained Si-on-Insulator Development Accelerates," Compound Semiconductor, April 2003.	<u></u>	

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Examiner	Date
Signature	Considered

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional). See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. Applicant is to place a check mark here if English language Translation is attached.